Unitized Semiconductor Devices - Page 1 of 1



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# Inclosure Material:

Ceramic

**Overall Length:** 

0.785 inches

# Terminal Length:

0.120 inches

### **Overall Height:**

0.280 inches

**Overall Width:** 

0.300 inches

### **End Application:**

Missile, all-weather antiship, harpoon (agm-84)

### **Mounting Facility Quantity:**

14

### **Component Name And Quantity:**

### 4 semiconductor device diode

Mounting Method:

Terminal

#### **Features Provided:**

Hermetically sealed case

# Criticality Code Justification:

Feat

#### Semiconductor Material:

Silicon all semiconductor

### Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, dc all semiconductor and 40.0 working peak off-state voltage all semiconductor

### **Power Rating Per Characteristic:**

1900.0 milliwatts small-signal input power, common-emitter absolute all semiconductor

### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius case

#### **Special Features:**

Weapon system essential

### **Terminal Type And Quantity:**

14 uninsulated wire lead

# Shelf Life:

N/a

### Unit Of Measure:

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### Demilitarization:

No

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